

Lecture 22: Linearity & Noise of Gilbert Mixers

Sources of NL

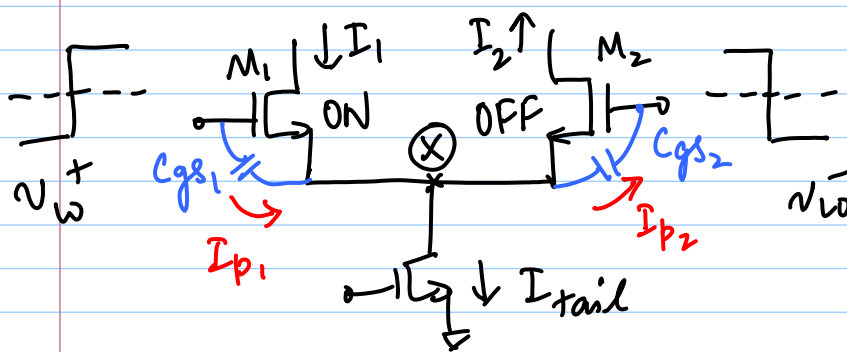
(i) Transconduct or Non-linearity

$$V_{DC} + V_{RF} \rightarrow \downarrow I_{out} = I_{DC} + g_{m0} V_{RF} + g_{m1} V_{RF}^2 + \dots$$

To improve $IP_3 \Rightarrow \uparrow V_{ov}$

BVT $\Rightarrow g_{m0} \downarrow \Rightarrow G_c \downarrow \Rightarrow NF \uparrow$

(ii) LO switch Non-linearity



$$C_{gs1} \approx \frac{2}{3} WL C_{ox}$$

$$C_{gs2} = WL_D C_{ox} \text{ (overlap cap)}$$

$$C_{gs1} \neq C_{gs2} \Rightarrow I_{p1} \neq I_{p2}$$

KCL @ node X

$$I_1 + I_{p1} = I_{p2} + I_T + \cancel{I_2} \quad (M_2 \text{ is OFF})$$

$$\Rightarrow I_1 = I_T + (I_{p2} - I_{p1})$$

$$\approx I_T - I_{p1} \quad (I_{p1} \gg I_{p2})$$

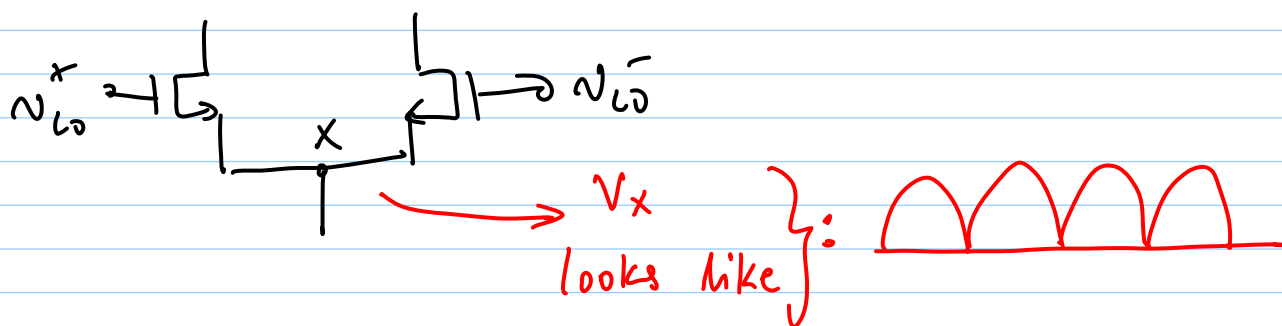
$$= I_T - C_{gs1} \frac{d(V_{LO} - V_X)}{dt}$$

displacement current flowing
into current source

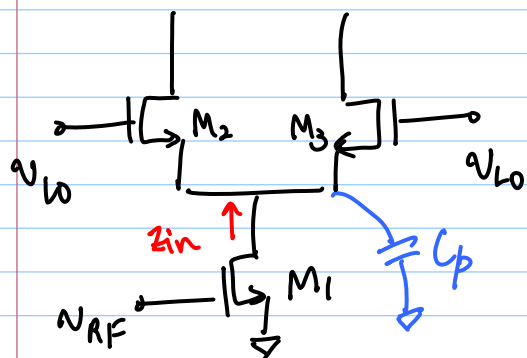
* I_1 is modulated by LO

→ if I_1 becomes small enough, M_1/M_2 may leave saturation \Rightarrow non-linearity

i.e. sharp LO edges & large v_{LO} make linearity worse (opposite of low-noise requirement - we will see this next class)



LO amplitude & LO switch size



* v_{LO} - large enough for 100% current switching

* Switching Speed depends on $v_{LO} \propto (V_{GS} - V_T)$
 V_{OV}

faster switching \leftrightarrow lower V_{OV}

$\uparrow W_{2,3} \Rightarrow$ low- Z path for I_{RF}

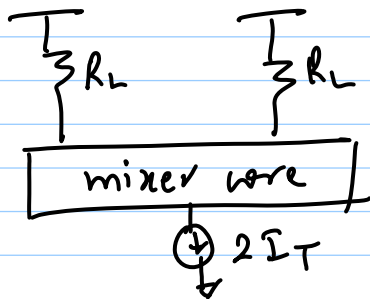
$\downarrow I_{DC} \Rightarrow g_{m_{2,3}} \downarrow \Rightarrow Z_{in} \uparrow$
 more I_{RF} through C_p

Noise in Gilbert Mixers:

Ref: H. Darabi & A. Abidi, "Noise in RF-CMOS mixers: A Simple Physical Model", IEEE Journal of Solid-State Circuits, Vol. 35, No. 1, Jan 2000, pp 15-25

1) Load Noise:

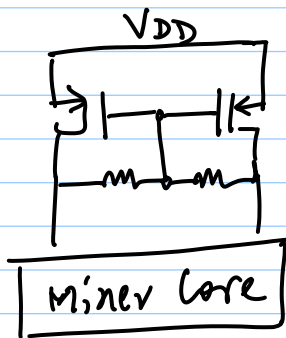
- a) Resistive load: * $\overline{v_{on,RL}^2} = 8kTR_L$ {2 resistors}
* no $1/f$ noise (usually)



Issues:

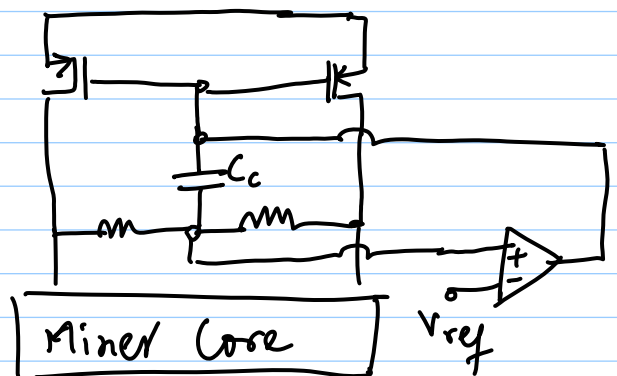
- * voltage headroom: $V_{o,cm} = V_{DD} - I_T R_L$
* $G_c \propto R_L$

b) PMOS loads



$$\rightarrow V_{o,cm} = V_{DD} - V_{GS}$$

CM - feedback



$$\rightarrow V_{o,cm} \leq V_{DD} - V_{D,SAT}$$

\rightarrow best headroom

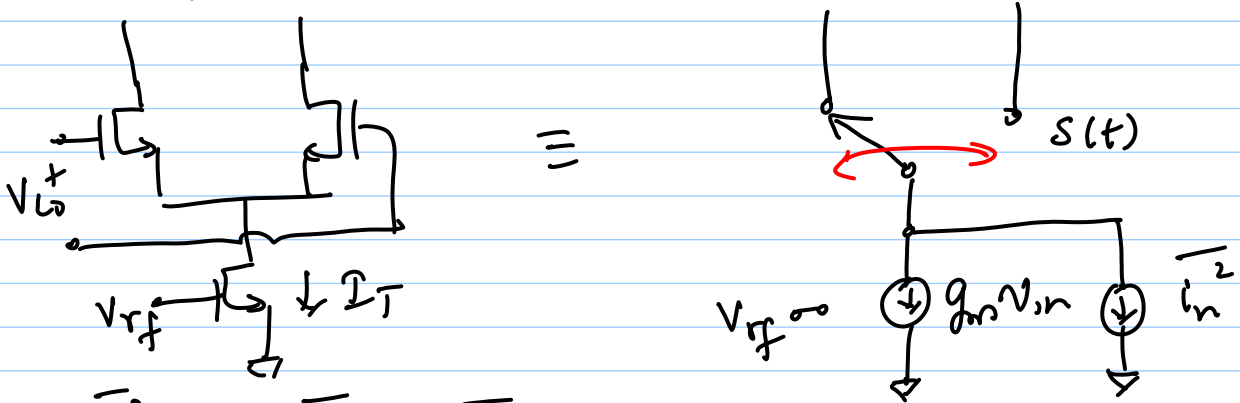
$\rightarrow C_c =$ Miller compensation cap

* Thermal noise of PMOS

* $1/f$ noise impacts direct conversion or low-IF R_x (use large PMOSs)

2) Noise from gm stage

Single-balanced mixer



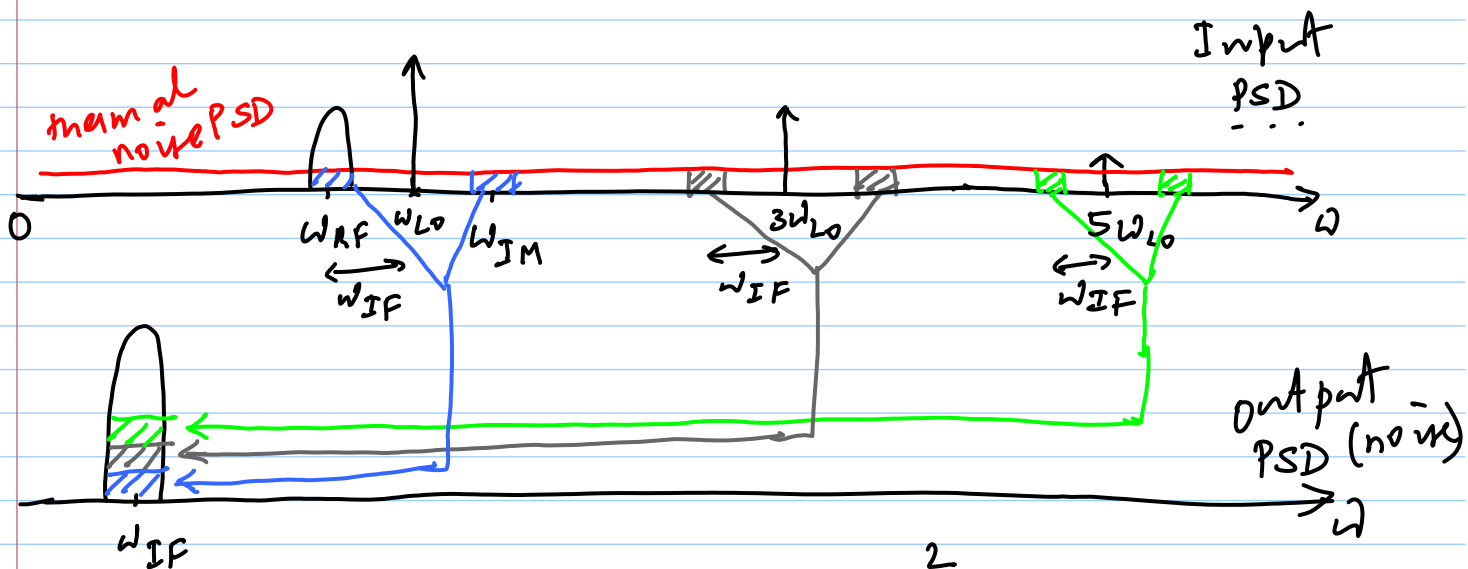
$$\overline{i_n^2} = \overline{i_d^2} + \overline{i_{1/f}^2}$$

* $\overline{i_n^2}$ gets amplitude modulated by $S(t)$

→ noise contribution from frequencies other than around f_{RF}

(a) thermal noise

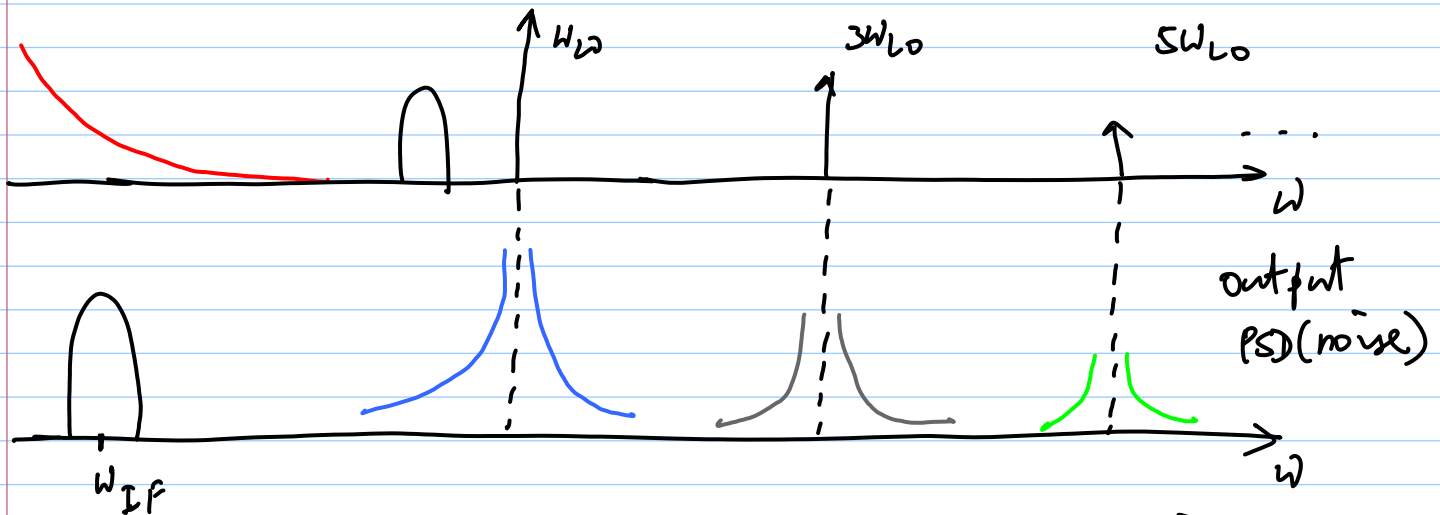
$$S(t) = \frac{2}{\pi} \sum_{n=1}^{\infty} \frac{1}{n} \sin(n\omega_{Lo}t), \quad n=\text{odd}$$



$$\frac{\overline{N_{on, gm}}}{\Delta f} \approx \underbrace{\frac{4KT}{g_m}}_{\text{Input noise PSD}} \times \underbrace{\left(\frac{2}{\pi} g_m R_L\right)^2}_{G_c^2} \times \underbrace{2 \times \left(1 + \frac{1}{3^2} + \frac{1}{5^2} + \dots\right)}_{= \pi^2/4}$$

$$\overline{v_{on, gm}^2} = 4kT \gamma g_m R_L^2$$

b) 1/f noise



Rx mixer : * very little impact from 1/f noise of g_m -stage

* Switching pair mismatch \Rightarrow some 1/f noise remains @ baseband

Tx mixer : desired signal = ω_{BB}

* (1/f noise + BB signal) gets up-converted

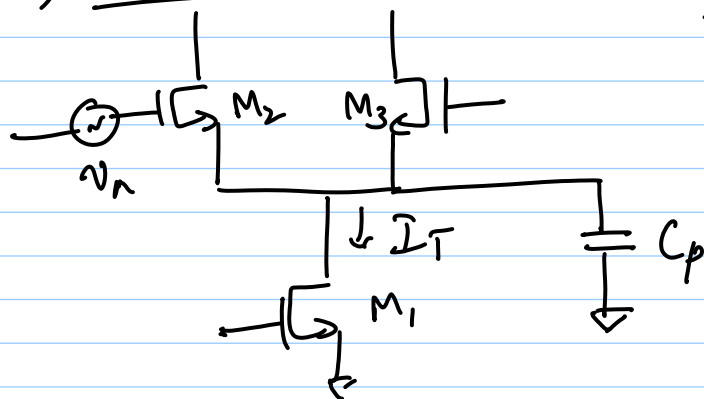
* 1/f noise does matter \Rightarrow design g_m stage with large area

3) Noise from switching pair :

\rightarrow more complicated to analyse

\rightarrow no noise contribution when current is completely switched (like a cascode)

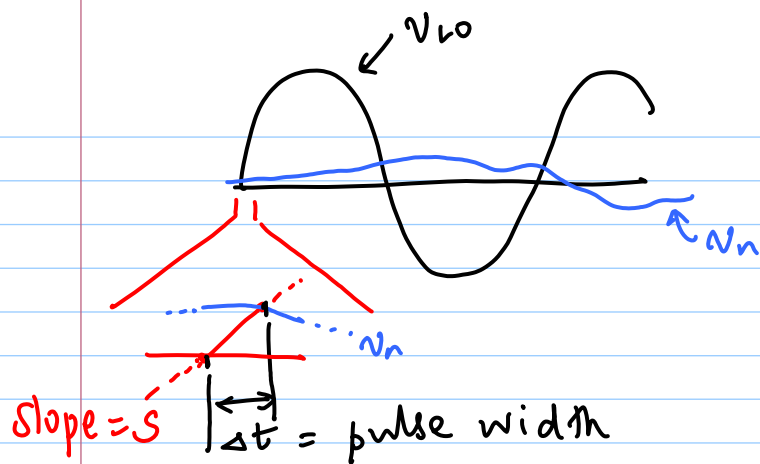
a) Direct switch noise



→ If C_p is large, switching devices do contribute noise even when fully on.
 {Ref. HW3 problem 3}

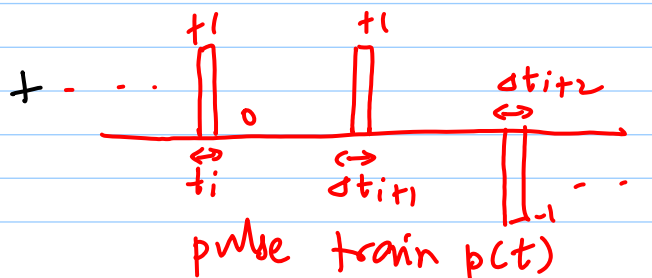
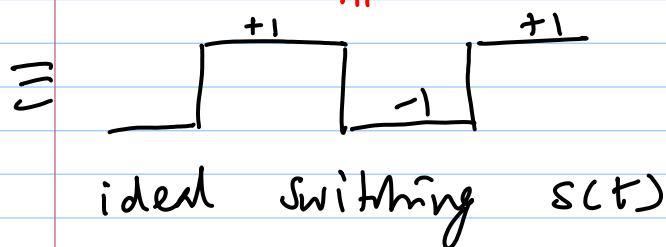
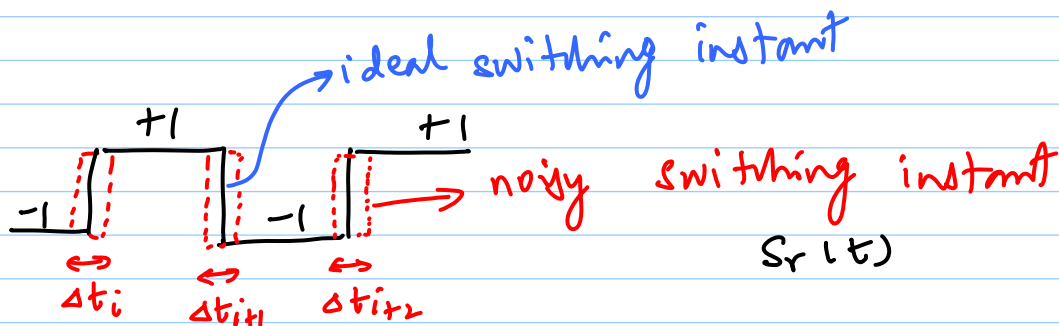
→ Both devices contribute noise during switching phase

→ \bar{v}_n = single input-referred noise source that captures noise of both switches M_2 - M_3
 * \bar{v}_n modulates the switching time instant



$$\Delta t = \frac{v_n(t)}{S}$$

$S \leftarrow$ slope @ switching instant



$$s_r(t) = s(t) + p(t)$$

$p(t)$ = pulse train of height = +1 or -1
width $\Delta t = \frac{v_n(t)}{S}$

$$\text{rate} = 2\omega_{L0}$$

$\bar{i}_{on} \Rightarrow$ pulses of amplitude $2I_T$

average value of output current over one period:

$$\begin{aligned}\bar{i}_{on} &= \frac{2}{T} \times 2I_T \times \Delta t = \frac{2}{T_{L0}} \times 2I_T \times \frac{V_n}{S} \\ &= 4I_T \cdot \frac{V_n}{S \cdot T_{L0}} \quad \left\{ T_{L0} = \frac{2\pi}{\omega_{L0}} \right\}\end{aligned}$$

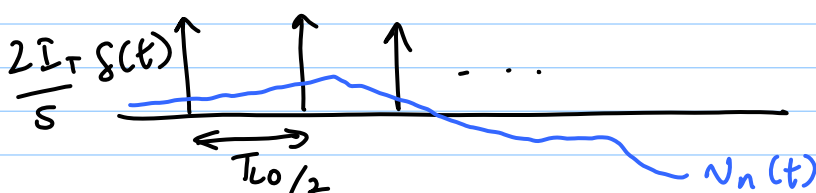
$$* L0 \text{ signal} = \pm V_{L0} \sin \omega_{L0} t \Rightarrow v_{L0d} = 2V_{L0} \sin \omega_{L0} t$$

$$\Rightarrow \text{slope} = \frac{dv_{L0d}}{dt} = 2V_{L0} \cdot \omega_{L0} \cos \omega_{L0} t$$

$$\begin{aligned}S &= \text{slope @ switching time } (t = n\pi/\omega_{L0}) \\ &= 2V_{L0} \cdot \omega_{L0}\end{aligned}$$

$$\begin{aligned}\Rightarrow S \cdot T &= 2V_{L0} \omega_{L0} \cdot T_{L0} \\ &= 4\pi V_{L0}\end{aligned}$$

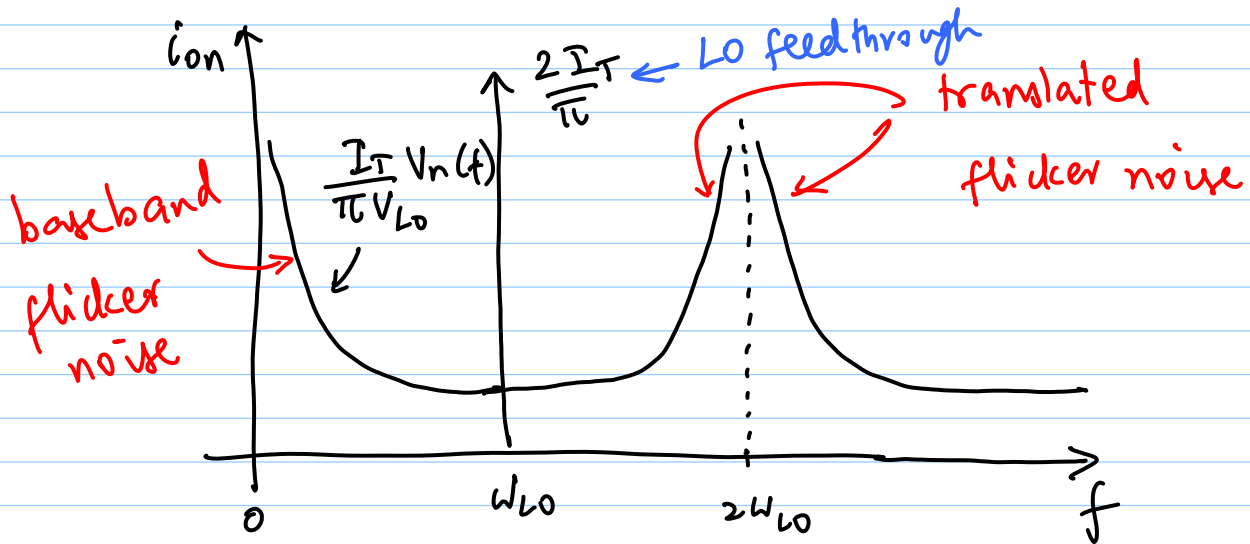
$\frac{\Delta t}{T_{L0}} \ll 1 \Rightarrow$ pulses are approximated by ideal δ -function impulses that sample $v_n(t)$



$$i_{on}(f) = \frac{4I}{S T_{L0}} V_n(f)$$

$$= \frac{1}{\pi} \cdot \frac{I_T}{V_{L0}} V_n(f) \quad \text{sampled images appear @ } n \cdot (2f_{L0})$$

Flicker noise



V.C. mixer (T_x) \rightarrow no $1/f$ noise from switches
 @ f_{L0}
 \rightarrow $1/f$ noise of g_m stage is present